

Gallium Arsenide Schottky Rectifier

I_{FAV} = 18 A
V_{RRM} = 220/250 V
C_{Junction} = 26 pF

Preliminary Data

V _{RSM} V	V _{RRM} V	Type
220	220	DGS 20-022A
250	250	DGS 20-025A
		}
		Single

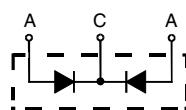
V _{RSM} V	V _{RRM} V	Type
220	220	DGSK 40-022A
250	250	DGSK 40-025A
		}
		Common cathode



TO-220 AC



A = Anode, C = Cathode , TAB = Cathode



TO-220 AB



Symbol	Conditions	Maximum Ratings	
I _{FAV}	T _C = 25°C; DC	18	A
I _{FAV}	T _C = 90°C; DC	13	A
I _{FSM}	T _{VJ} = 45°C; t _p = 10 ms (50 Hz), sine	30	A
T _{VJ}		-55...+175	°C
T _{stg}		-55...+150	°C
P _{tot}	T _C = 25°C	48	W
M _d	mounting torque	0.4...0.6	Nm

Features

- Low forward voltage
- Very high switching speed
- Low junction capacity of GaAs
- low reverse current peak at turn off
- Soft turn off
- Temperature independent switching behaviour
- High temperature operation capability
- Epoxy meets UL 94V-0

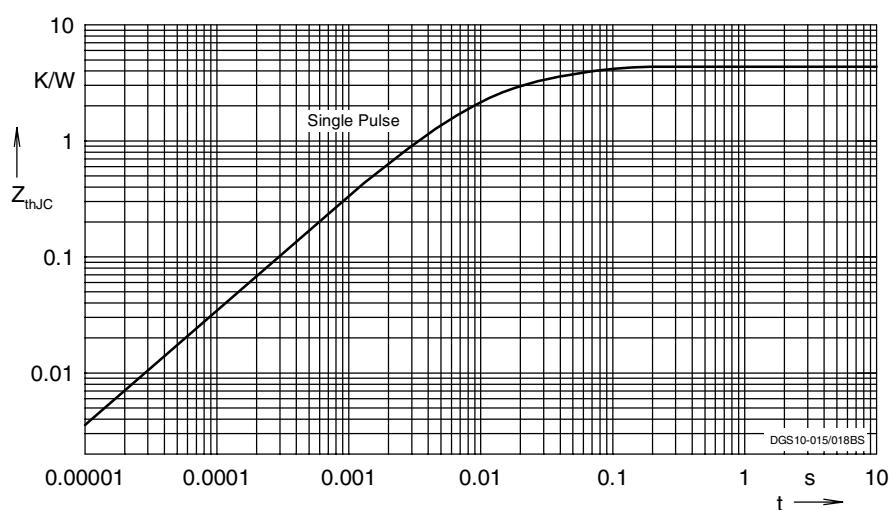
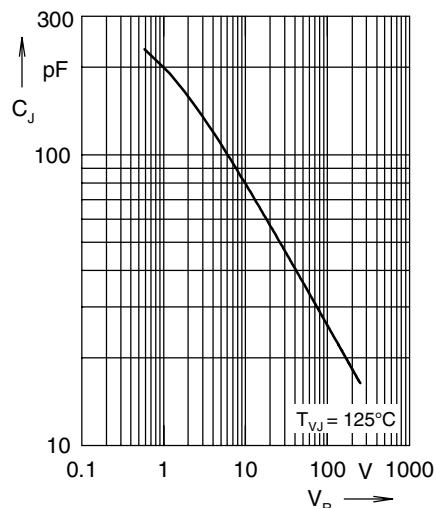
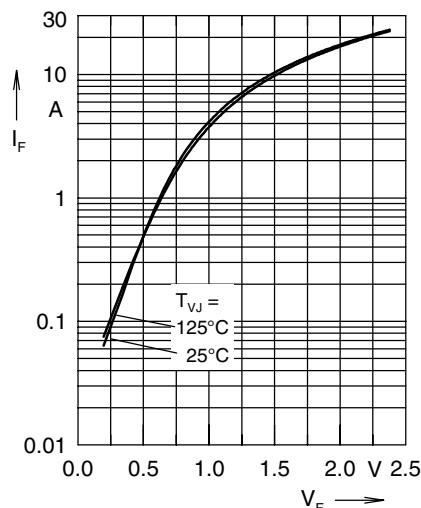
Applications

- MHz Switched mode power supplies (SMPs)
- Small size SMPs
- High frequency converters
- Resonant converters

Symbol	Conditions	Characteristic Values	
		typ.	max.
I _R ①	T _{VJ} = 25°C V _R = V _{RRM} T _{VJ} = 125°C V _R = V _{RRM}	2.0	2.0 mA
V _F	I _F = 7.5 A; T _{VJ} = 125°C I _F = 7.5 A; T _{VJ} = 25°C	1.3 1.2	1.5 V
C _J	V _R = 100 V; T _{VJ} = 125°C	26	pF
R _{thJC}		3.1	K/W
R _{thCH}		0.5	K/W
Weight		2	g

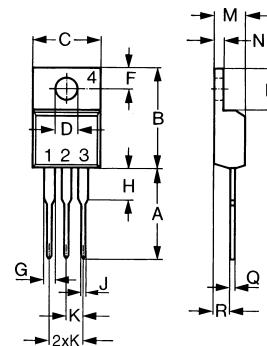
Pulse test: ① Pulse Width = 5 ms, Duty Cycle < 2.0 %
Data according to IEC 60747 and per diode unless otherwise specified

IXYS reserves the right to change limits, Conditions and dimensions.


Note:

explanatory comparison of the basic operational behaviour of rectifier diodes and Gallium Arsenide Schottky diodes:

	Rectifier Diode	GaAs Schottky Diode
conduction forward characteristics	by majority + minority carriers V_F (I_F)	by majority carriers only V_F (I_F), see Fig. 1
turn off characteristics	extraction of excess carriers causes temperature dependant reverse recovery (t_{rr} , I_{RM} , Q_m)	reverse current charges junction capacity C_J , see Fig. 2; not temperature dependant
turn on characteristics	delayed saturation leads to V_{FR}	no turn on overvoltage peak

Outline (center pin only for DGSK types)


Dim.	Millimeter Min.	Millimeter Max.	Inches Min.	Inches Max.
A	12.70	13.97	0.500	0.550
B	14.73	16.00	0.580	0.630
C	9.91	10.66	0.390	0.420
D	3.54	4.08	0.139	0.161
E	5.85	6.85	0.230	0.270
F	2.54	3.18	0.100	0.125
G	1.15	1.65	0.045	0.065
H	2.79	5.84	0.110	0.230
J	0.64	1.01	0.025	0.040
K	2.54	BSC	0.100	BSC
M	4.32	4.82	0.170	0.190
N	1.14	1.39	0.045	0.055
Q	0.38	0.56	0.015	0.022
R	2.29	2.79	0.090	0.110